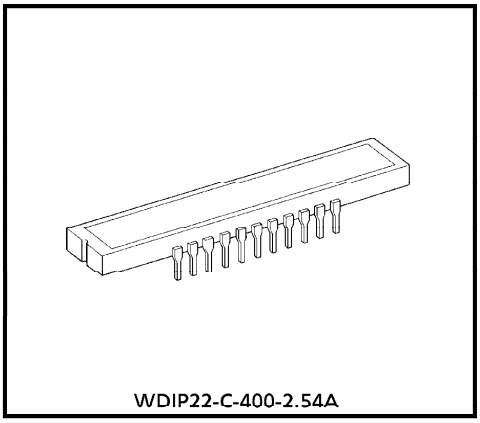
TOSHIBA CCD LINEAR IMAGE SENSOR CCD(Charge Coupled Device)

TCD2301C

The TCD2301C which includes sample-and-hold circuit and clamp circuit is a high sensitive and low dark current 3648 elements × 3 lines CCD color image sensor. The sensor is designed for color scanner.
The device contains a row of 3648 elements × 3 lines photodiodes which provide a 16 lines / mm across a A4 size paper. The device is operated by 5V pulse, and 12V power supply.



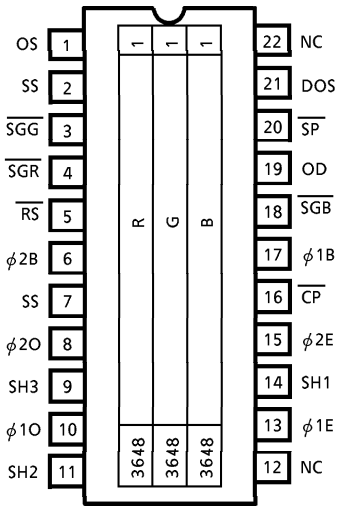
WDIP22-C-400-2.54A

Weight : 4.8g (Typ.)

FEATURES

- Number of Image Sensing Elements : 3648 elements × 3 lines
- Image Sensing Element Size : 8μm by 8μm on 8μm centers
- Photo Sensing Region : High sensitive pn photodiode
- Distance Between Photodiode Array : 96μm (12 Lines)
- Clock : 2 phase (5V)
- Internal Circuit : Sample & Hold circuit, Clamp circuit
- Package : 22 pin DIP
- Color Filter : Red, Green, Blue

PIN CONNECTIONS



(TOP VIEW)

MAXIMUM RATINGS (Note 1)

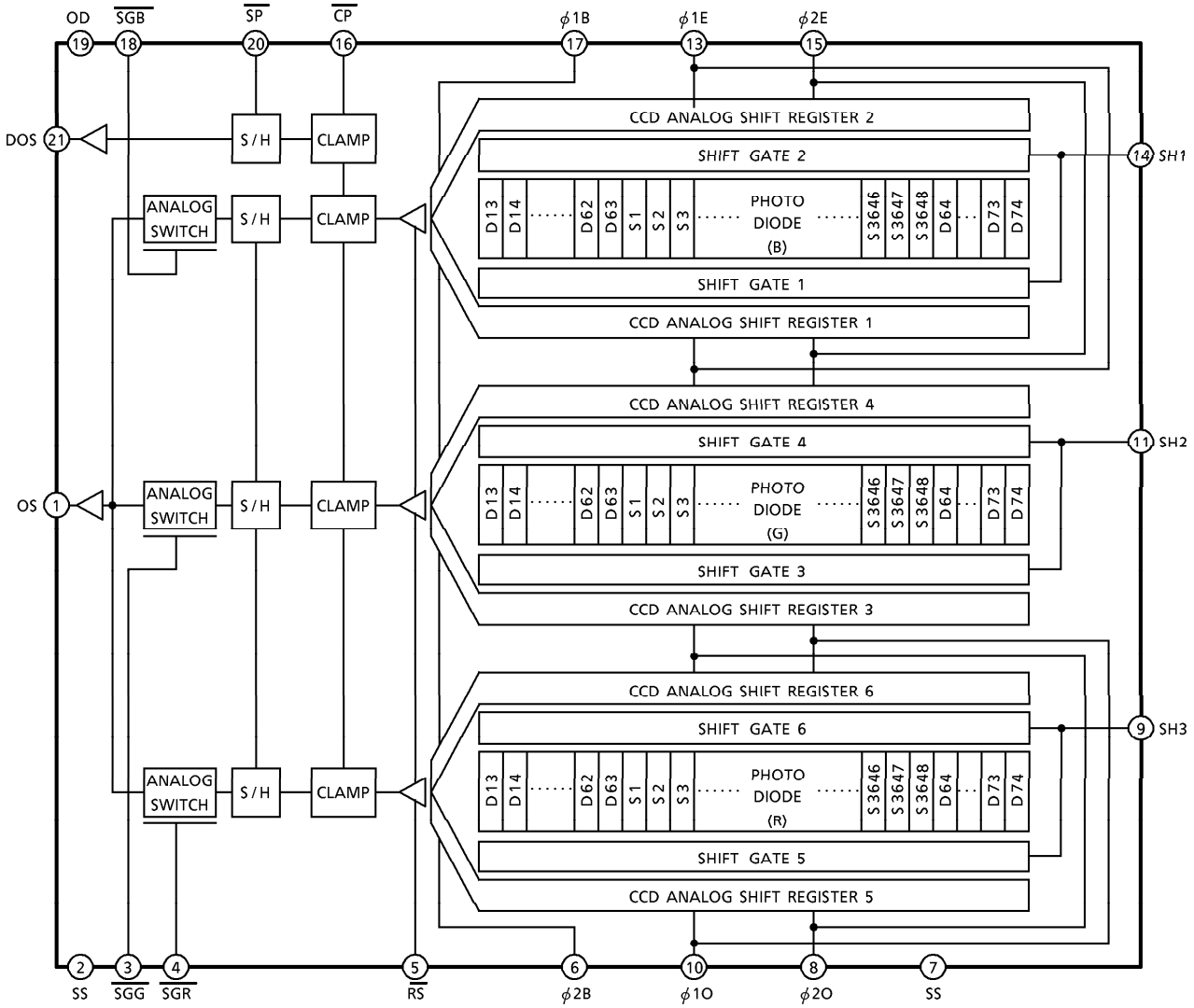
CHARACTERISTIC	SYMBOL	RATING	UNIT
Clock Pulse Voltage	V_{ϕ}	−0.3~8	V
Shift Pulse Voltage	V_{SH}		
Reset Pulse Voltage	$V_{\overline{RS}}$		
Sample and Hold Pulse Voltage	$V_{\overline{SP}}$		
Switch Pulse Voltage	$V_{\overline{SG}}$		
Clamp Pulse Voltage	$V_{\overline{CP}}$		
Power Supply Voltage	V_{OD}	−0.3~15	V
Operating Temperature	T_{opr}	0~60	°C
Storage Temperature	T_{stg}	−25~85	°C

(Note 1) All voltage are with respect to SS terminals (Ground).

961001EBA2

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CIRCUIT DIAGRAM



PIN NAMES

ϕ1E	Clock 1 (Phase 1)	SH3	Shift Gate 3
ϕ2E	Clock 2 (Phase 2)	$\overline{RS}$	Reset Gate
ϕ1O	Clock 1 (Phase 1)	$\overline{SP}$	Sample and Hold Gate
ϕ2O	Clock 2 (Phase 2)	$\overline{SGR}$	R Switch
ϕ1B	Final Stage Clock (Phase 1)	$\overline{SGG}$	G Switch
ϕ2B	Final Stage Clock (Phase 2)	$\overline{SGB}$	B Switch
SS	Ground	$\overline{CP}$	Clamp Gate
OD	Power	OS	Signal Output
SH1	Shift Gate 1	DOS	Compensation Output
SH2	Shift Gate 2	NC	Non Connection

961001EBA2'

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- The information contained herein is subject to change without notice.

OPTICAL / ELECTRICAL CHARACTERISTICS

(Ta = 25°C, V_{OD} = 12V, $V_\phi = V_{\overline{RS}} = V_{SH} = V_{\overline{CP}}$ = 5V (Pulse), f_ϕ = 0.5MHz, $f_{\overline{RS}}$ = 1.0MHz, Load Resistance = 100kΩ, t_{INT} (Integration Time) = 10ms, Light Source = A Light Source + CM500 Filter (t = 1.0mm))

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Sensitivity (Red)	RR	—	1.1	—	V / lx·s	(Note 2)
Sensitivity (Green)	RG	—	1.4	—	V / lx·s	(Note 2)
Sensitivity (Blue)	RB	—	0.5	—	V / lx·s	(Note 2)
Photo Response Non Uniformity	PRNU (1)	—	10	20	%	(Note 3)
	PRNU (3)	—	3	12	mV	(Note 4)
Register Imbalance	RI	—	—	3	%	(Note 5)
Saturation Output Voltage	V_{SAT}	1.0	1.5	—	V	(Note 6)
Saturation Exposure	SE	—	1.07	—	lx·s	(Note 7)
Dark Signal Voltage	V_{DRK}	—	—	2.0	mV	(Note 8)
Dark Signal Non Uniformity	DSNU	—	—	3.0	mV	(Note 9)
Total Transfer Efficiency	TTE	92	—	—	%	
Output Impedance	Z_o	—	0.5	1.0	kΩ	
DC Power Dissipation	P_D	—	500	750	mW	
DC Offset Voltage	V_{OS}	—	6.0	—	V	(Note 10)
DC Compensation Output Voltage	V_{DOS}	—	6.0	—	V	(Note 10)
DC Mismach Voltage	$\lvert V_{OS}-V_{DOS}\rvert$	—	100	300	mV	(Note 10)

(Note 2) Sensitivity is defined for each color of signal outputs average when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

(Note 3) PRNU (1) is defined for each color on a single chip by the expressions below when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

$$\text{PRNU (1)} = \frac{\Delta\chi}{\overline{\chi}} \times 100 \ (\%)$$

Where $\overline{\chi}$ is average of total signal outputs and $\Delta\chi$ is the maximum deviation from $\overline{\chi}$.

The amount of the incident light is shown below.

$$\text{Red} = \frac{1}{2} \text{ SE}$$

$$\text{Green} = \frac{1}{2} \text{ SE}$$

$$\text{Blue} = \frac{1}{4} \text{ SE}$$

(Note 4) PRNU (3) is defined as maximum voltage with next pixel, where measured 5% of SE (TYP.).

(Note 5) RI is defined for each color on a single chip by the expressions below when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

$$RI = \frac{\sum_{n=1}^{3647} |\chi n - \chi n + 1|}{3647 \times \overline{\chi}} \times 100\ (\%)$$

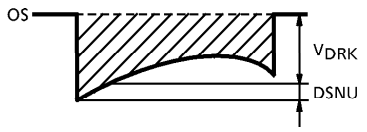
Where χn and $\chi n + 1$ are signal outputs of each pixel. $\overline{\chi}$ is average of total signal outputs.

(Note 6) V_{SAT} is defined as minimum Saturation Output Voltage of all effective pixels.

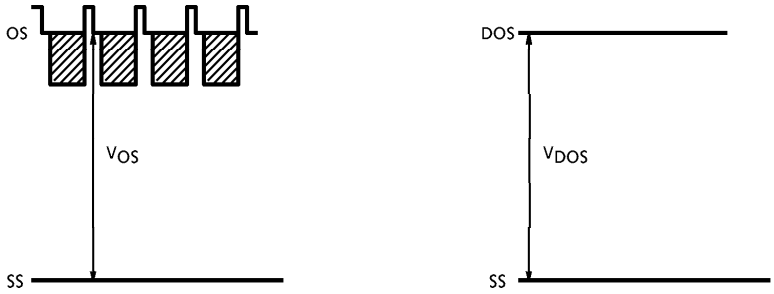
(Note 7) Definition of SE : $SE = \frac{V_{SAT}}{RG}$

(Note 8) V_{DRK} is defined as average dark signal voltage of all effective pixels.

(Note 9) DSNU is defined as different voltage between V_{DRK} and V_{MDK}, when V_{MDK} is maximum dark voltage.



(Note 10) DC Signal Output Voltage and DC Compensation Output Voltage are defined as follows:



OPERATING CONDITION

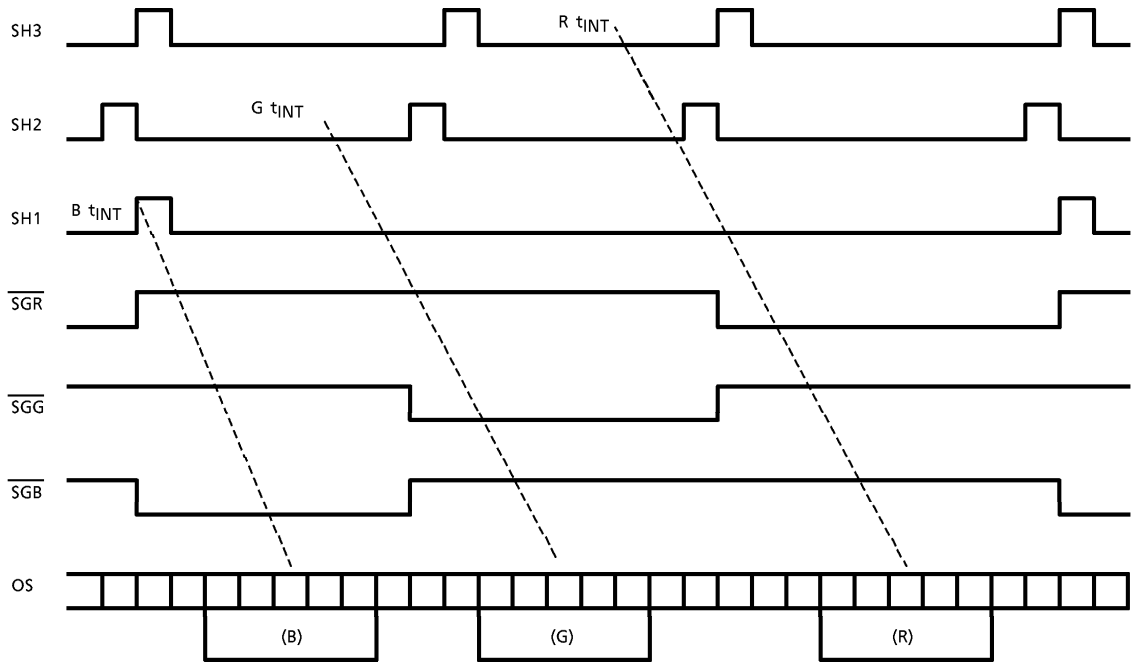
CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Clock Pulse Voltage	"H" Level	$V_{\phi 0, E}$	4.5	5.0	5.5	V	
	"L" Level		0.0	0.2	0.5		
Final Stage Clock Pulse Voltage	"H" Level	$V_{\phi B}$	4.5	5.0	5.5	V	
	"L" Level		0.0	0.2	0.5		
Shift Pulse Voltage	"H" Level	V_{SH}	$V_{\phi 0}$,E"H" – 1	$V_{\phi 0}$, E "H"	$V_{\phi 0}$, E "H"	V	(Note 11)
	"L" Level		0.0	0.2	0.5		
Reset Pulse Voltage	"H" Level	$V_{\overline{RS}}$	4.5	5.0	5.5	V	
	"L" Level		0.0	0.2	0.5		
Sample and Hold Pulse Voltage	"H" Level	$V_{\overline{SP}}$	4.5	5.0	5.5	V	(Note 12)
	"L" Level		0.0	0.2	0.5		
RGB Switch Pulse Voltage	"H" Level	$V_{\overline{SG}}$	4.5	5.0	5.5	V	
	"L" Level		0.0	0.2	0.5		
Clamp Pulse Voltage	"H" Level	$V_{\overline{CP}}$	4.5	5.0	5.5	V	(Note 13)
	"L" Level		0.0	0.2	0.5		
Power Supply Voltage		V_{OD}	11.4	12.0	13.0	V	

(Note 11) $V_{\phi 0}$, E "H" means the high level voltage of $V_{\phi 0}$ and $V_{\phi E}$ when SH pulse is high level.
(Note 12) Supply "L" level to $\overline{SP}$ terminal when sample-and-hold circuit is not used.
(Note 13) Supply $\overline{SH}$ (inversed pulse of SH) to $\overline{CP}$ terminal when clamp circuit is not used.

CLOCK CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Frequency	f_{ϕ}	—	0.5	2.0	MHz
Reset Pulse Frequency	$f_{\overline{RS}}$	—	1.0	4.0	MHz
Sample and Hold Pulse Frequency	$f_{\overline{SP}}$	—	1.0	4.0	MHz
Clamp Pulse Frequency	$f_{\overline{CP}}$	—	1.0	4.0	MHz
Clock Capacitance	$C_{\phi 0, E}$	—	500	—	pF
Final Stage Clock Capacitance	$C_{\phi B}$	—	10	—	pF
Shift Gate Capacitance	C_{SH}	—	200	—	pF
Reset Gate Capacitance	$C_{\overline{RS}}$	—	10	—	pF
Sample and Hold Gate Capacitance	$C_{\overline{SP}}$	—	10	—	pF
RGB Switch Pulse Capacitance	$C_{\overline{SG}}$	—	10	—	pF
Clamp Gate Capacitance	$C_{\overline{CP}}$	—	10	—	pF

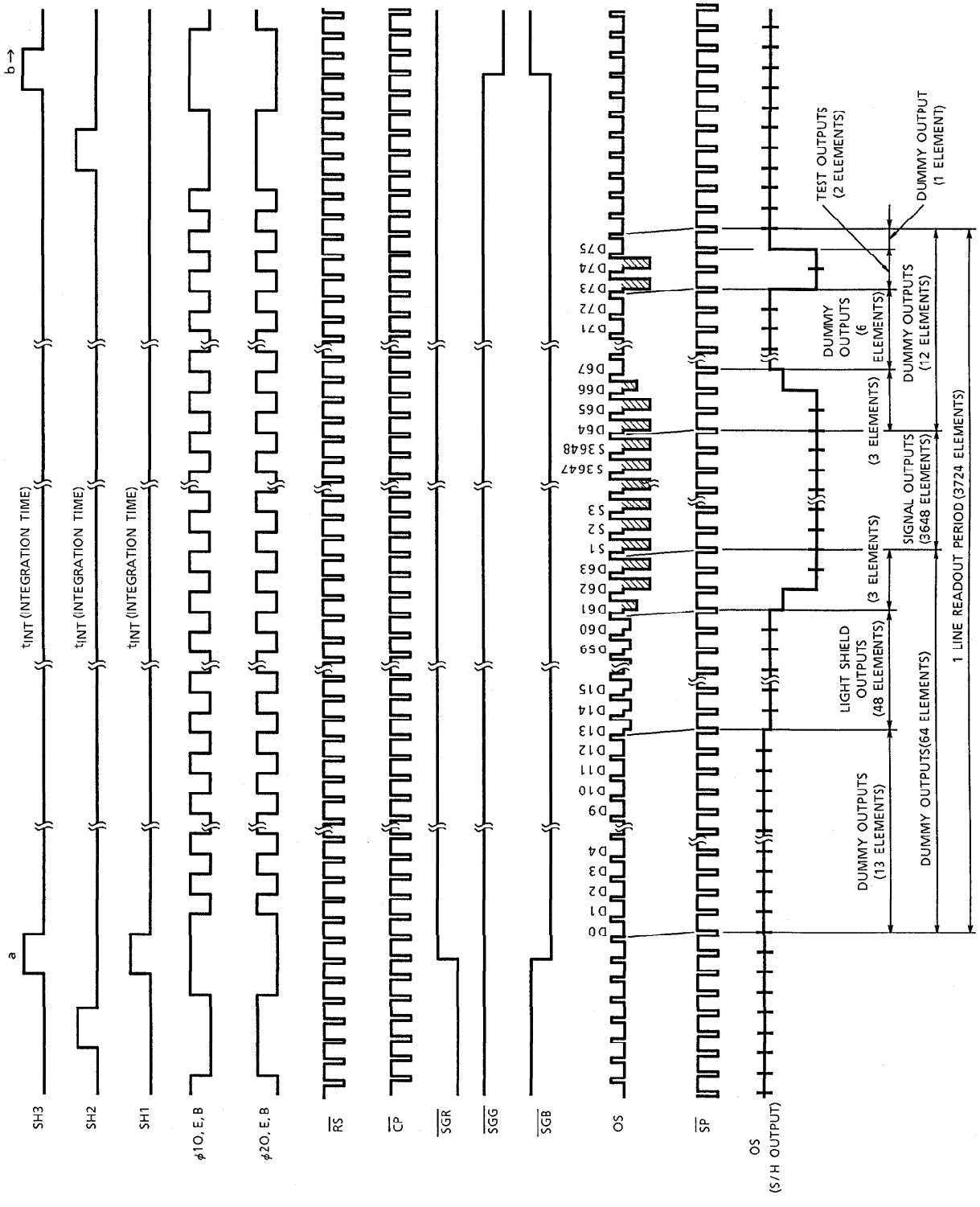
APPLICATION NOTE



a) You drive TCD2301C by above timing, so you can get the three output signal of nearly equal level.

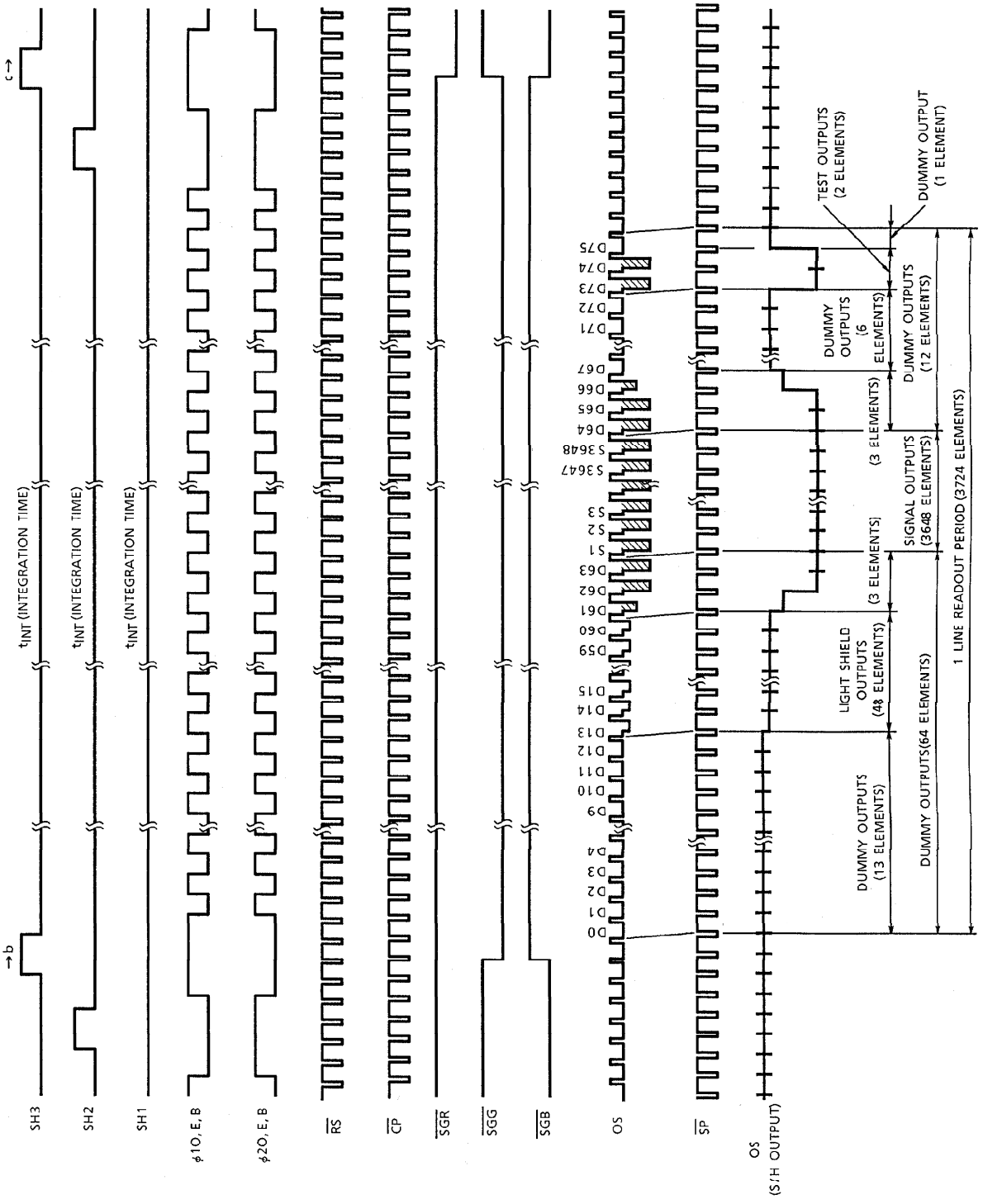
b) In switching "$\overline{SGR}$", "$\overline{SGG}$" and "$\overline{SGB}$", asynchronous switching operation with clock pulse, shift pulse or any other input pulses timing, is possible. (It is not necessary to switch above timing shown in figure.) But care should be taken not to make more than two switches to "L" level at the same time.

TIMING CHART 1



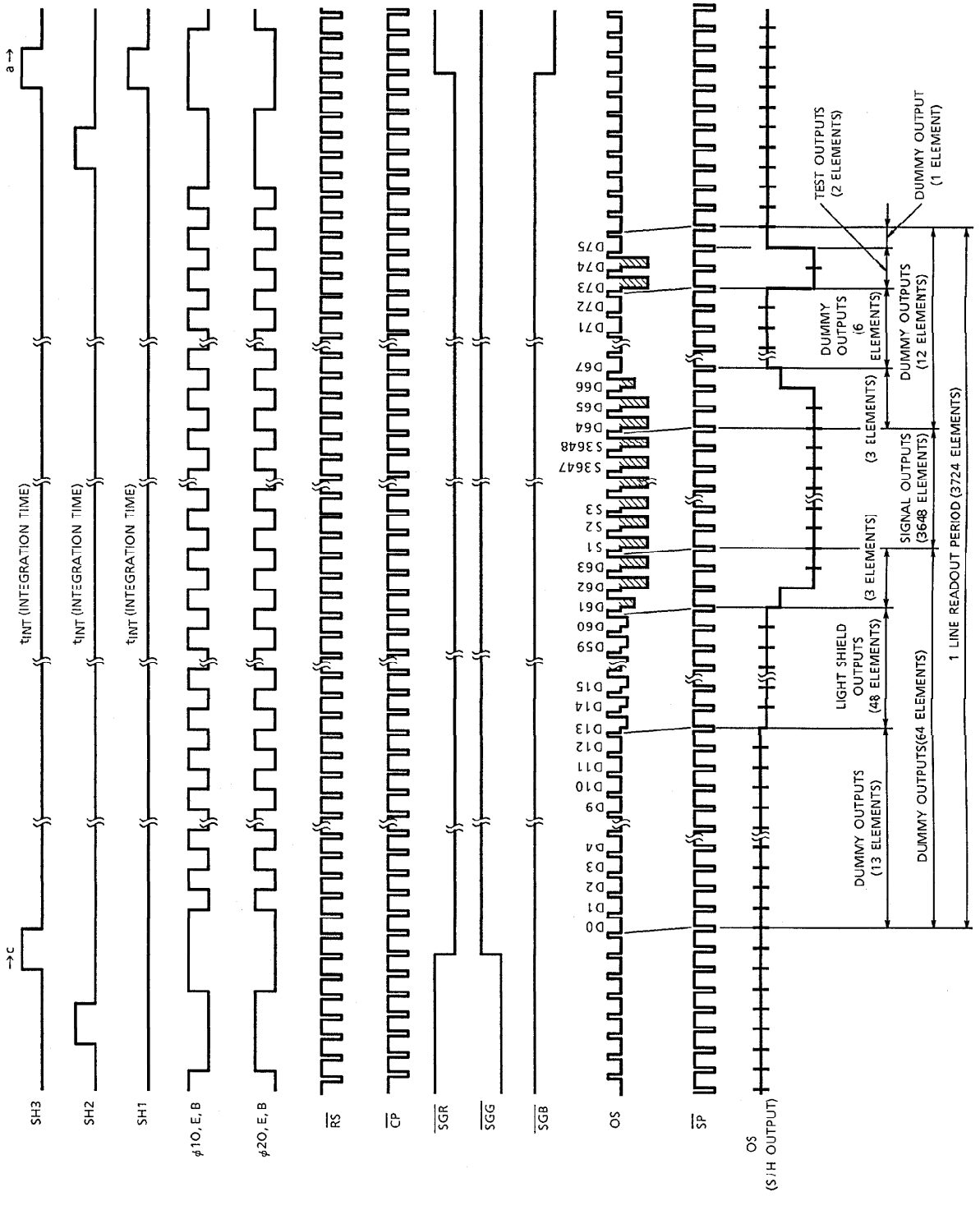
TCD2301C(E) – 7

TIMING CHART 2



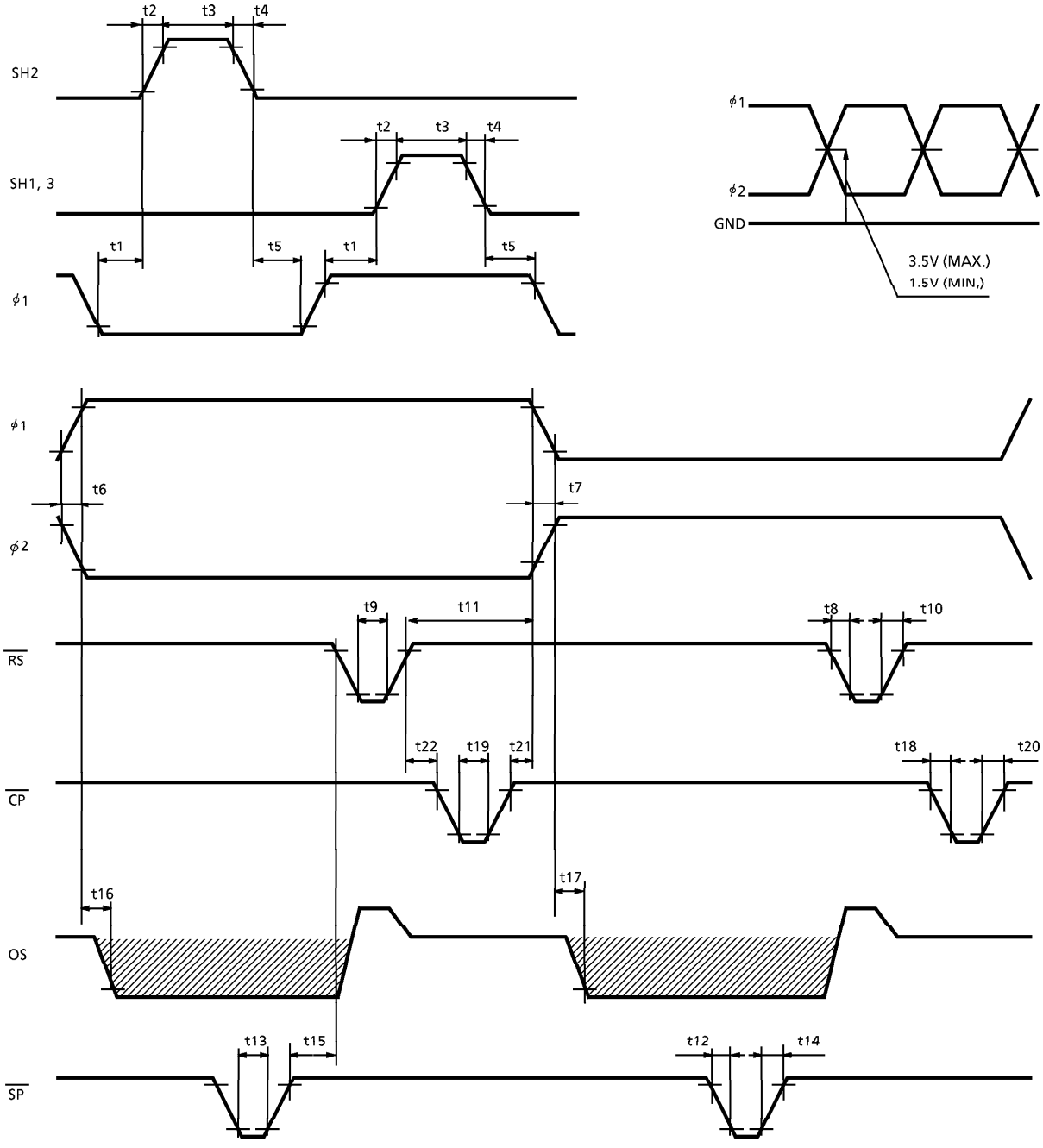
TCD2301C(E)-8

TIMING CHART 3



TCD2301C(E) - 9

TIMING REQUIREMENTS

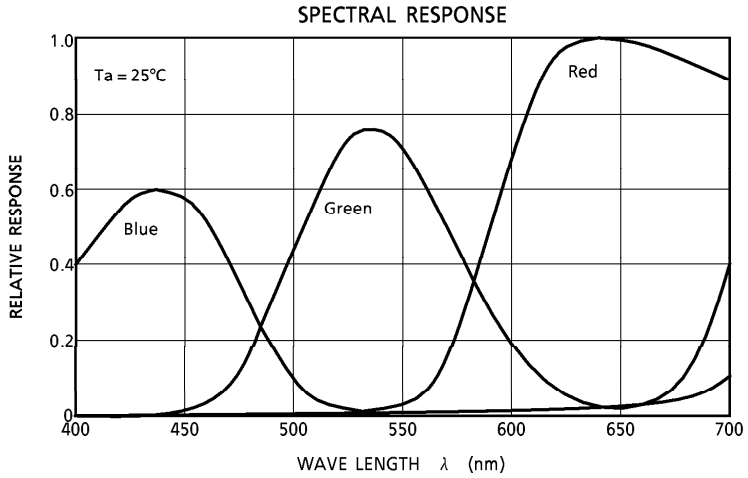


TIMING REQUIREMENTS (Cont'd)

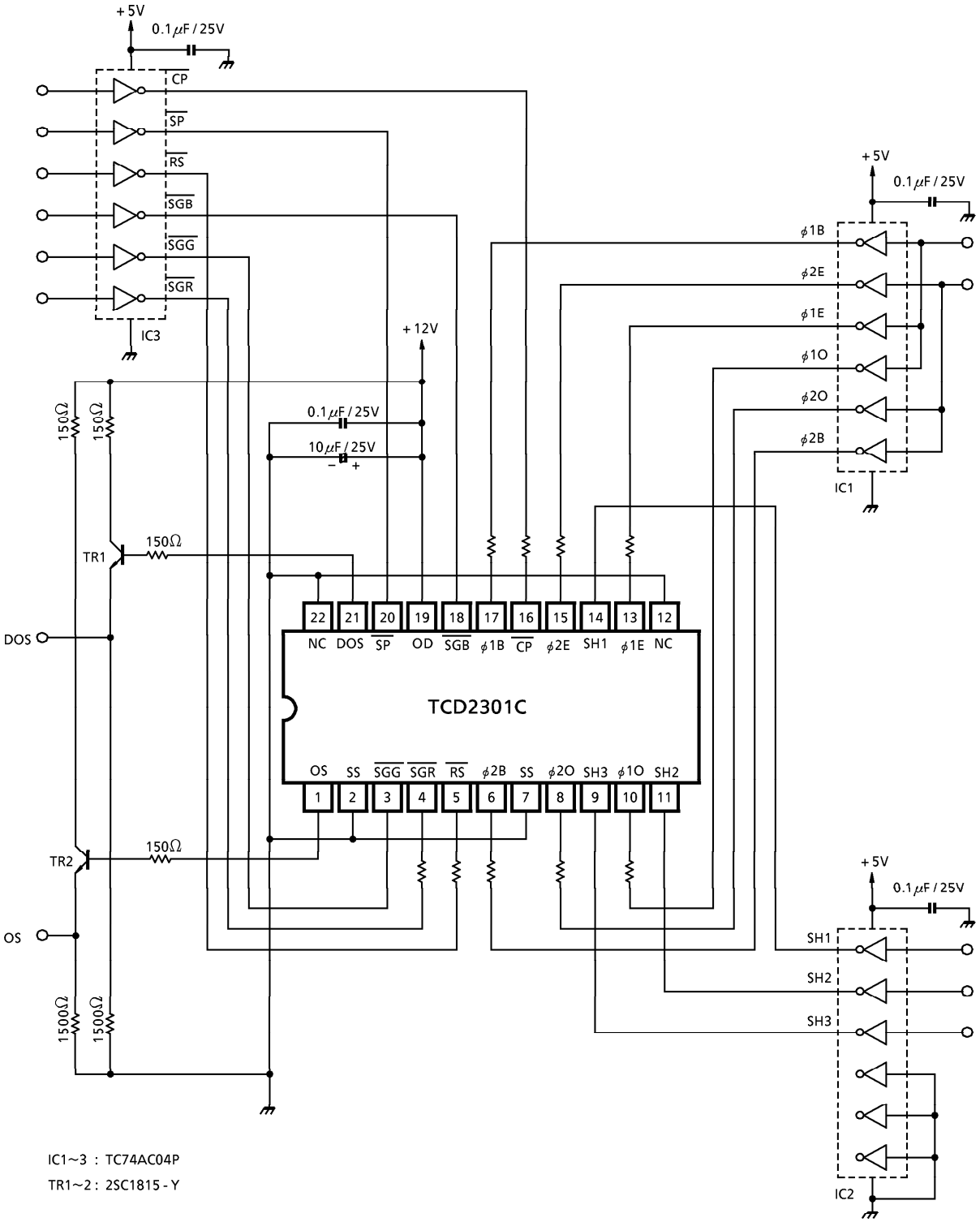
CHARACTERISTIC	SYMBOL	MIN.	TYP. (Note 14)	MAX.	UNIT
Pulse Timing of SH and ϕ0, E	t1, t5	0	1000	—	ns
SH Pulse Rise Time, Fall Time	t2, t4	0	50	—	ns
SH Pulse Width	t3	500	1000	—	ns
ϕ1, ϕ2 Pulse Rise Time, Fall Time	t6, t7	0	50	—	ns
$\overline{RS}$ Pulse Rise Time, Fall Time	t8, t10	0	20	—	ns
$\overline{RS}$ Pulse Width	t9	40	250	—	ns
Pulse Timing of ϕ1B, ϕ2B and $\overline{RS}$	t11	120	300	—	ns
$\overline{SP}$ Pulse Rise Time, Fall Time	t12, t14	0	20	—	ns
$\overline{SP}$ Pulse Width	t13	70	100	—	ns
Pulse Timing of $\overline{SP}$ and $\overline{RS}$	t15	0	50	—	ns
Video Data Delay Time (Note 15)	t16, t17	—	70	—	ns
$\overline{CP}$ Pulse Rise Time, Fall Time	t18, t20	0	20	—	ns
$\overline{CP}$ Pulse Width	t19	100	200	—	ns
Pulse Timing of ϕ1B, ϕ2B and $\overline{CP}$	t21	20	50	—	ns
Pulse Timing of $\overline{RS}$ and $\overline{CP}$	t22	0	50	—	ns

(Note 14) TYP. is the case of $f_{\overline{RS}}$ = 1.0MHz
(Note 15) Load Resistance is 100kΩ

TYPICAL SPECTRAL RESPONSE



TYPICAL DRIVE CIRCUIT



CAUTION

1. Window Glass

   The dust and stain on the glass window of the package degrade optical performance of CCD sensor.
   Keep the glass window clean by saturating a cotton swab in alcohol and lightly wiping the surface, and allow the glass to dry, by blowing with filtered dry N2.
   Care should be taken to avoid mechanical or thermal shock because the glass window is easily to damage.

2. Electrostatic Breakdown

   Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

3. Incident Light

   CCD sensor is sensitive to infrared light.
   Note that infrared light component degrades resolution and PRNU of CCD sensor.

4. Lead Frame Forming

   Since this package is not shoutagainst mechanical stress, you should not reform the lead frame.
   We recommend to use a IC-inserter when you assemble to PCB.

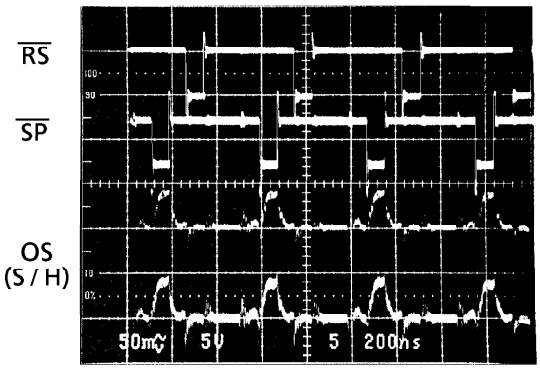
<Application note>

EVEN-ODD UNBALANCE

When High-speed draiving standard level of odd-even bits is often unbalanced. For that reason when high-speed draiving CCD you should put a damping resistance in input ϕ pin.

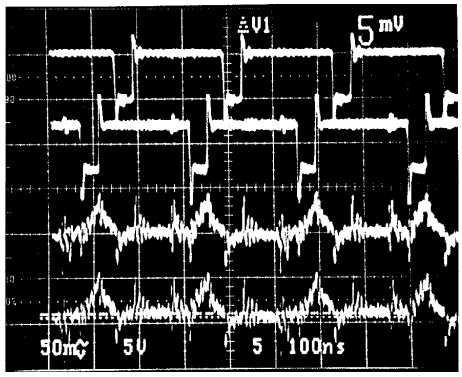
1. WAVEFORM (Sample and Hold ON)

fDATA = 2MHz

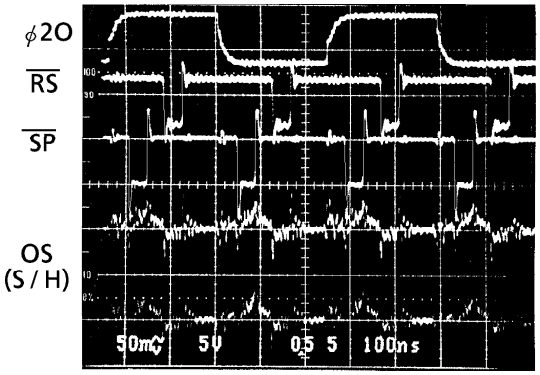


← Dark Signal →

fDATA = 4MHz

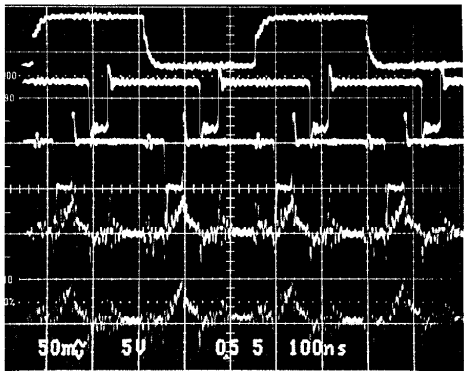


Without A Damping Resistance



← Dark Signal →

Without A Damping Resistance



2. MEASUREMENT CONDITION

Ta = 25°C, $V_{AD} = V_{DD} = 12V$,

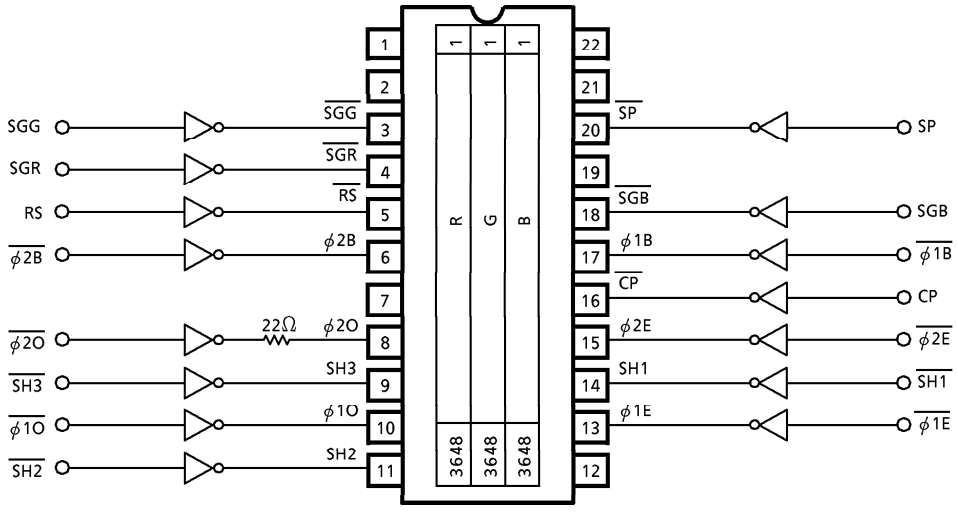
$V_{\phi 1E} = V_{\phi 10} = V_{\phi 1B} = V_{\phi 2E} = V_{\phi 20} = V_{\phi 2B} = V_{\overline{RS}} = V_{\overline{CP}} = V_{\overline{SP}} = V_{SH1} = V_{SH2} = V_{SH3} = 5V$ (Pulse),
Light Source = Daylight Fluorescent Lamp.

Ocilloscope	Tektoronix	2465A (400MHz)
Probe	P6136	10.8pF

3. DRIVE CIRCUIT (with a damping resistance)

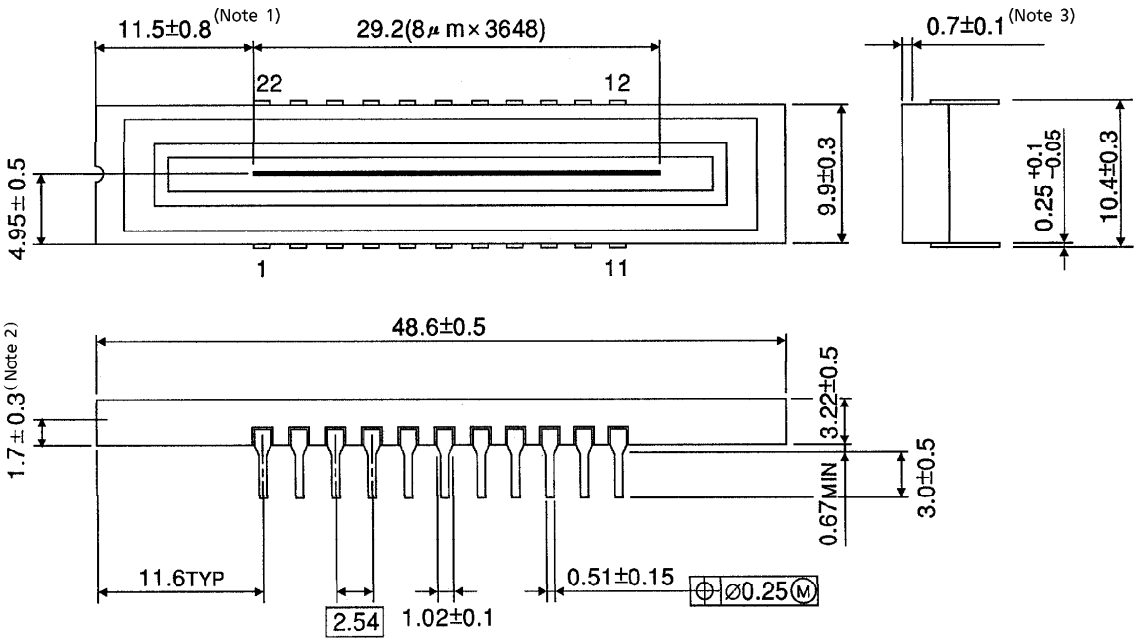
Please put a damping resistance in input ϕ20 (22Ω).

TCD2301C



OUTLINE DRAWING

WDIP22-C-400-2.54A (C) Unit : mm



(Note 1) No. 1 SENSOR ELEMENT (S1) TO EDGE OF PACKAGE.
(Note 2) TOP OF CHIP TO BOTTOM OF PACKAGE.
(Note 3) GLASS THICKNES (n = 1.5)

Weight : 4.8g (Typ.)